

PHOTO-INTERRUPTER

KTIR0821DS

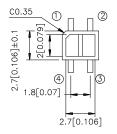
Features

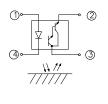
- Compact and thin
- •Visible light cut-off type
- High sensitivity
- •RoHS Compliant.

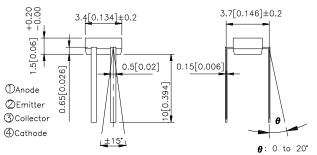
Applications

- •Cassette tape recorders, VCRs
- •Floppy disk drives
- •Various microcomputerized control equipment

Package Dimensions







Notes

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- 3. Lead spacing is measured where the lead emerge package.
- 4. Specifications are subject to change without notice.

Absolute Maximum Ratings (T_a=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Reverse voltage	V _R	6	V
	Power dissipation	Р	75	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	Ic	50	mA
	Collector power dissipation	P _c	75	mW
Operating temperature		Topr	-25~+85	°C
Storage temperature		Tstg	-40~+100	°C
Soldering temperature (1/16 inch from body for 5 seconds)		Tsol	260	°C

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REV NO: V.3 CHECKED: Allen Liu DATE: DEC/02/2004 DRAWN: L.Y.WU PAGE: 1 OF 4



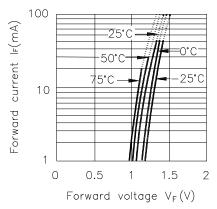
Electro-optical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input	Forward voltage		V _F	I _F =20mA	1.0	1.2	1.5	V
	Reverse current		I _R	V _R =6V	_	_	10	μΑ
Output	Collector dark current		I _{ceo}	V _{CE} =10V,I _F =0mA	ı	-	10-6	Α
Transfer charact- eristics	*1Collector currer	nt	Ic	V _{CE} =2V,I _F =4mA	_	3	ı	mA
	*2Leak current		I _{LEAK}	V _{CE} =5V,I _F =4mA	-	_	5	μΑ
	Response time	Rise time	t,	V_{CE} =2V,I $_{C}$ =10mA R $_{L}$ =100 Ω ,d=1mm	_	80	400	μsec
		Fall time	t _f		_	70	400	μsec

^{*1} The condition and arrangement of the reflective object are shown below

Test Condition and Al evaporation Arrangement for 11mm-thick glass Collector Current

Fig.1 Forward Current vs. **Forward Voltage**



30

Fig.2 Collector Current vs.

Forward Current

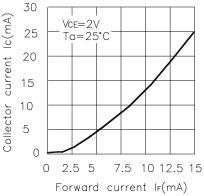


Fig.3 Collector Current vs. Collector-emitter Voltage

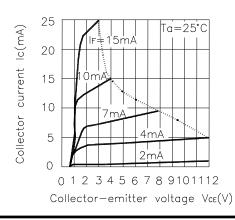
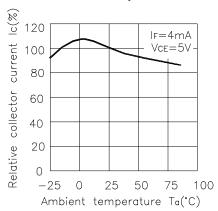


Fig.4 Relative Collector Current vs. **Ambient Temperature**



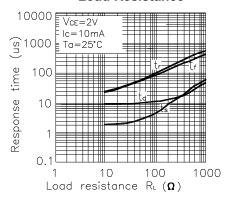
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^{*2} Without reflective object

Kingbright

Fig.5 Response Time vs **Load Resistance**



Test Circuit for Response Time

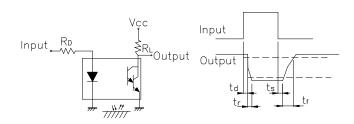


Fig.6 Collector Dark Current vs **Ambient Temperature**

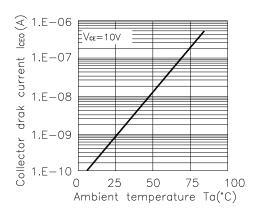


Fig.7 Relative Collector Current vs Distance between Sensor and **Al Evaporation Glass**

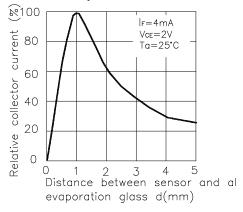


Fig.8 Relative Collector Current vs. Card Moving Distance (1)

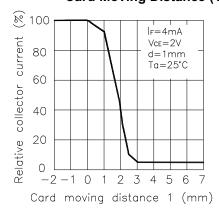
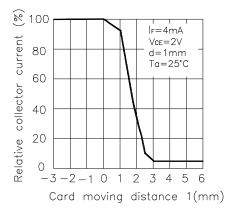


Fig.9 Relative Collector Current vs. Card Moving Distance (2)



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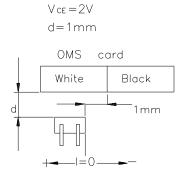
Test Condition for Distance&Detecting Position Characteristics

Correpond to Fig.7

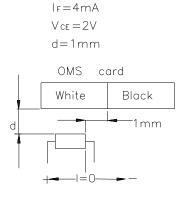


Correpond to Fig.8 Test condition

 $I_F = 4mA$



Correpond to Fig.9 Test condition



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